

MBRF2040 CT – MBRF20200CT

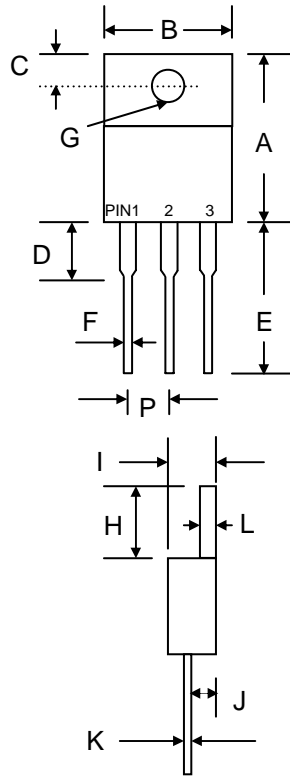
20.0A SCHOTTKY BARRIER DIODE

Features

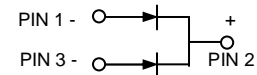
- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- For Use in Low Voltage Application
- Guard Ring Die Construction
- Plastic Case Material has UL Flammability Classification Rating 94V-O

Mechanical Data

- Case: TO-220F, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Mounting Position: Any
- **Lead Free: For RoHS / Lead Free Version**



TO-220F		
Dim	Min	Max
A	14.50	15.50
B	9.50	10.50
C	2.55	2.90
D	3.30	4.30
E	13.00	14.00
F	0.30	0.90
G	3.00 Ø	3.80 Ø
H	6.30	7.30
I	4.20	4.80
J	2.50	2.90
K	0.47	0.75
L	2.50	3.10
P	2.35	2.75
All Dimensions in mm		



Maximum Ratings and Electrical Characteristics @ $T_A=25^\circ\text{C}$ unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	MBRF 2040 CT	MBRF 2045 CT	MBRF 2050 CT	MBRF 2060 CT	MBRF 20100 CT	MBRF 20150 CT	MBRF 20200 CT	Units	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	40	45	50	60	100	150	200	V	
RMS Reverse Voltage	$V_{R(RMS)}$	28	31	35	42	70	105	140	V	
Average Rectified Output Current @ $T_L = 75^\circ\text{C}$ (Note 1)	I_O	20.0							A	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	150							A	
Forward Voltage @ $I_F = 10\text{A}$	V_{FM}	0.70	0.80		0.85		0.92		V	
Peak Reverse Current @ $T_A = 25^\circ\text{C}$ At Rated DC Blocking Voltage @ $T_A = 100^\circ\text{C}$	I_{RM}	0.1				20			mA	
Typical Junction Capacitance (Note 2)	C_j	350	280		200				pF	
Typical Thermal Resistance (Note 1)	$R_{\theta JA}$	3.0				2.0				$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_j, T_{STG}	-55 to +150					-55 to +175			$^\circ\text{C}$

Note: 1. Valid provided that leads are kept at ambient temperature at a distance of 9.5mm from the case.
2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

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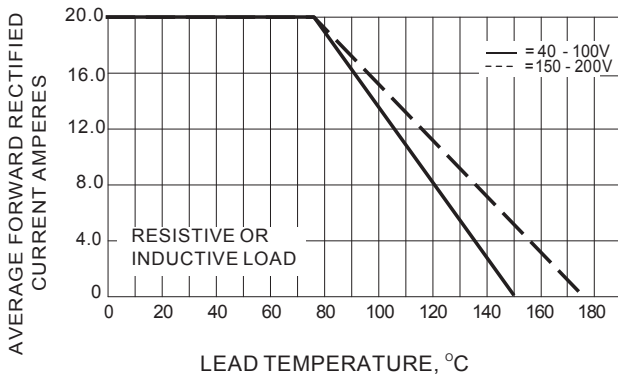


Fig.1- FORWARD CURRENT DERATING CURVE

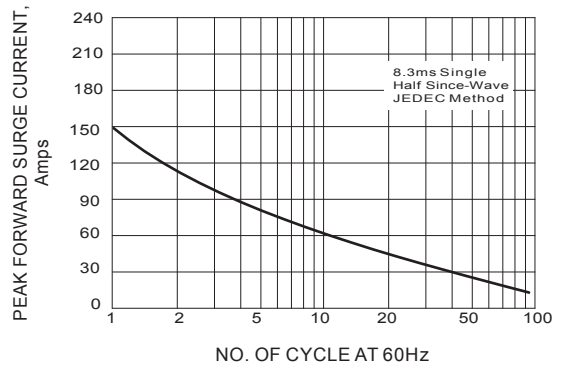


Fig.2- MAXIMUM NON-REPETITIVE SURGE CURRENT

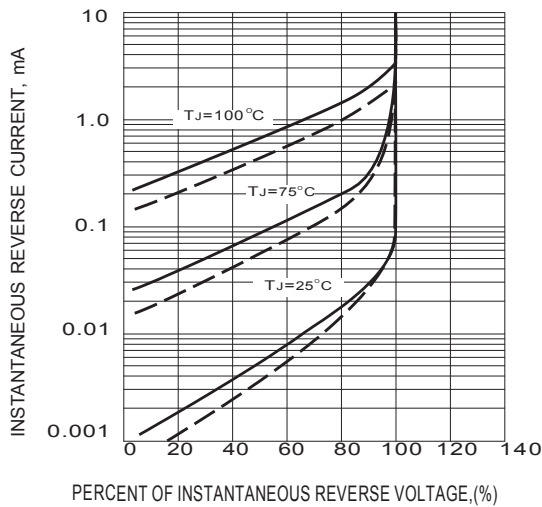


Fig.3- TYPICAL REVERSE CHARACTERISTICS

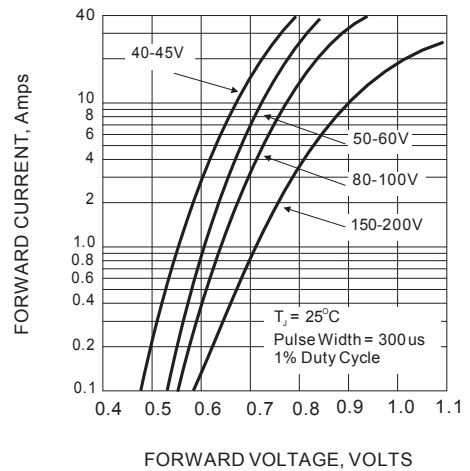


Fig.4- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS